SN54HC374, SN74HC374 OCTAL EDGE-TRIGGERED D-TYPE FLIP-FLOPS WITH 3-STATE OUTPUTS

SCLS141B - DECEMBER 1982 - REVISED MAY 1997

- Eight D-Type Flip-Flops in a Single Package
- High-Current 3-State True Outputs Can Drive up to 15 LSTTL Loads
- Full Parallel Access for Loading
- Package Options Include Plastic Small-Outline (DW), Thin Shrink Small-Outline (PW), and Ceramic Flat (W) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (N) and Ceramic (J) 300-mil DIPs

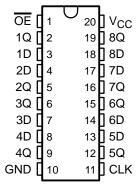
description

These 8-bit flip-flops feature 3-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. They are particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers.

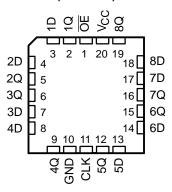
The eight flip-flops of the 'HC374 are edge-triggered D-type flip-flops. On the positive transition of the clock (CLK) input, the Q outputs are set to the logic levels that were set up at the data (D) inputs.

An output-enable (\overline{OE}) input places the eight outputs in either a normal logic state (high or low logic levels) or the high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without interface or pullup components.

SN54HC374...J OR W PACKAGE SN74HC374...DW, N, OR PW PACKAGE (TOP VIEW)



SN54HC374 . . . FK PACKAGE (TOP VIEW)



OE does not affect the internal operations of the flip-flops. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

The SN54HC374 is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74HC374 is characterized for operation from –40°C to 85°C.

FUNCTION TABLE (each flip-flop)

	INPUTS	OUTPUT				
OE	CLK	D	Q			
L	\uparrow	Н	Н			
L	\uparrow	L	L			
L	H or L	Χ	Q_0			
Н	Х	Χ	Z			

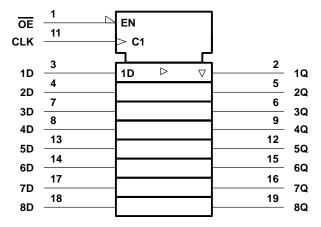


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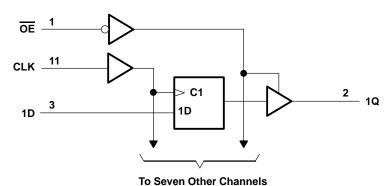
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logic symbol†



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range‡

Supply voltage range, V _{CC}		–0.5 V to 7 V
Input clamp current, I_{IK} ($V_I < 0$ or $V_I > V_{CC}$) (see	e Note 1)	±20 mA
Output clamp current, I_{OK} ($V_O < 0$ or $V_O > V_{CC}$)) (see Note 1)	±20 mA
Continuous output current, $I_O(V_O = 0 \text{ to } V_{CC})$.		±35 mA
Continuous current through V _{CC} or GND		±70 mA
Package thermal impedance, θ_{JA} (see Note 2): I		
1	N package	67°C/W
	PW package	128°C/W
Storage temperature range, T _{Stq}		-65° C to 150° C

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
 - 2. The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace length of zero.



recommended operating conditions

			SN	154HC37	4	SN74HC374			UNIT
			MIN	NOM	MAX	MIN	NOM	MAX	UNII
Vcc	Supply voltage		2	5	6	2	5	6	V
		V _{CC} = 2 V	1.5			1.5			
VIН	/IH High-level input voltage	V _{CC} = 4.5 V	3.15			3.15			V
		V _{CC} = 6 V	4.2			4.2			
	Low-level input voltage	V _{CC} = 2 V	0		0.5	0		0.5	
VIL		V _{CC} = 4.5 V	0		1.35	0		1.35	V
		V _{CC} = 6 V	0		1.8	0		1.8	
٧ _I	Input voltage		0		VCC	0		VCC	V
٧o	Output voltage		0		VCC	0		VCC	V
		V _{CC} = 2 V	0		1000	0		1000	
t _t	Input transition (rise and fall) time	$V_{CC} = 4.5 \text{ V}$	0		500	0		500	ns
		V _{CC} = 6 V	0		400	0		400	
TA	Operating free-air temperature		-55		125	-40		85	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DADAMETED	TEST CONDITIONS		V	T _A = 25°C			SN54HC374		SN74HC374		LINUT
PARAMETER			vcc	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
			2 V	1.9	1.998		1.9		1.9		
		I _{OH} = -20 μA	4.5 V	4.4	4.499		4.4		4.4		
Voн	VI = VIH or VIL		6 V	5.9	5.999		5.9		5.9		V
		$I_{OH} = -6 \text{ mA}$	4.5 V	3.98	4.3		3.7		3.84		
		$I_{OH} = -7.8 \text{ mA}$	6 V	5.48	5.8		5.2		5.34		
	VI = VIH or VIL	I _{OL} = 20 μA	2 V		0.002	0.1		0.1		0.1	
			4.5 V		0.001	0.1		0.1		0.1	
VOL			6 V		0.001	0.1		0.1		0.1	V
		$I_{OL} = 6 \text{ mA}$	4.5 V		0.17	0.26		0.4		0.33	
		$I_{OL} = 7.8 \text{ mA}$	6 V		0.15	0.26		0.4		0.33	
lį	$V_I = V_{CC}$ or 0		6 V		±0.1	±100		±1000		±1000	nA
loz	$V_O = V_{CC}$ or 0		6 V		±0.01	±0.5		±10		±5	μΑ
^I CC	$V_I = V_{CC}$ or 0,	I _O = 0	6 V			8		160		80	μΑ
C _i			2 V to 6 V		3	10		10		10	рF

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timing requirements over recommended operating free-air temperature range (unless otherwise noted)

		V	T _A = :	25°C	SN54F	IC374	SN74H	IC374	UNIT
		v _{CC}	MIN	MAX	MIN	MAX	MIN	MAX	UNII
		2 V	0	6	0	4	0	5	
fclock	Clock frequency	4.5 V	0	30	0	20	0	24	MHz
		6 V	0	35	0	24	0	28	
t _W	Pulse duration, CLK high or low	2 V	80		120		100		
		4.5 V	16		24		20		ns
		6 V	14		20		17		
	Setup time, data before CLK↑	2 V	100		150		125		ns
t _{su}		4.5 V	20		30		25		
		6 V	17		25		21		
	Hold time, data after CLK↑	2 V	10		13		12		ns
th		4.5 V	5		5		5		
		6 V	5		5		5		

switching characteristics over recommended operating free-air temperature range, C_L = 50 pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	V	T,	գ = 25°C	;	SN54H	IC374	SN74H	IC374	UNIT		
PARAMETER	(INPUT)	(OUTPUT)	VCC	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNII		
			2 V	6	12		4		5				
f _{max}			4.5 V	30	60		20		24		MHz		
			6 V	35	70		24		28				
			2 V		63	180		270		225			
^t pd	CLK	Any Q	4.5 V		17	36		54		45	ns		
					6 V		15	31		46		38	
			2 V		60	150		225		190			
t _{en}	ŌĒ	Any Q	4.5 V		16	30		45		38	ns		
			6 V		14	26		38		32			
			2 V		36	150		225		190			
^t dis	ŌĒ	Any Q	4.5 V		17	30		45		38	ns		
			6 V		16	26		38		32			
			2 V		28	60		90		75			
t _t		Any Q	4.5 V		8	12		18		15	ns		
			6 V		6	10		15		13			

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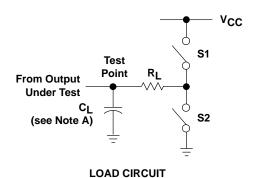
switching characteristics over recommended operating free-air temperature range, C_L = 150 pF (unless otherwise noted) (see Figure 1)

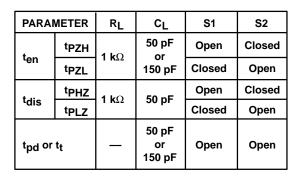
PARAMETER	FROM TO		V	T,	λ = 25°C	;	SN54HC374		SN74HC374		UNIT
PARAMETER	(INPUT)	(OUTPUT)	VCC	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
			2 V	6	12				5		
f _{max}			4.5 V	30	60				24		MHz
			6 V	35	70				28		
	CLK	Any Q	2 V		80	230		345		290	
t _{pd}			4.5 V		22	46		69		58	ns
			6 V		19	39		58		49	
	ŌĒ	Any Q	2 V		70	200		300		250	
t _{en}			4.5 V		25	40		60		50	ns
			6 V		22	34		51		43	
		Any Q	2 V		45	210		315		265	
t _t			4.5 V		17	42		63		53	ns
,			6 V		13	36		53		45	

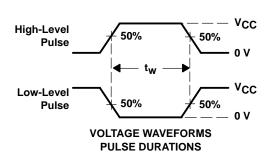
operating characteristics, $T_A = 25^{\circ}C$

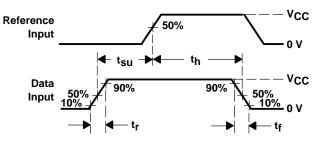
	PARAMETER	TEST CONDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance per flip-flop	No load	100	pF

PARAMETER MEASUREMENT INFORMATION

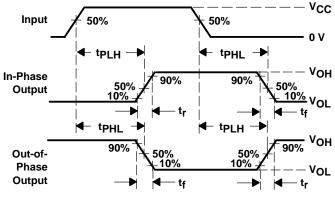


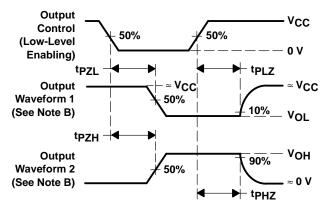






VOLTAGE WAVEFORMS
SETUP AND HOLD AND INPUT RISE AND FALL TIMES





VOLTAGE WAVEFORMS
PROPAGATION DELAY AND OUTPUT TRANSITION TIMES

VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES FOR 3-STATE OUTPUTS

NOTES: A. C_L includes probe and test-fixture capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, Z_O = 50 Ω , t_f = 6 ns.
- D. For clock inputs, f_{max} is measured when the input duty cycle is 50%.
- E. The outputs are measured one at a time with one input transition per measurement.
- F. tpLz and tpHz are the same as tdis.
- G. tpZL and tpZH are the same as ten.
- H. tpLH and tpHL are the same as tpd.

Figure 1. Load Circuit and Voltage Waveforms



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